

Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company

MANAGEMENT SERVICE



TO-237 Plastic Package

NPN SILICON PLANAR EPITAXIAL TRANSISTORS



Complementary CTN 369

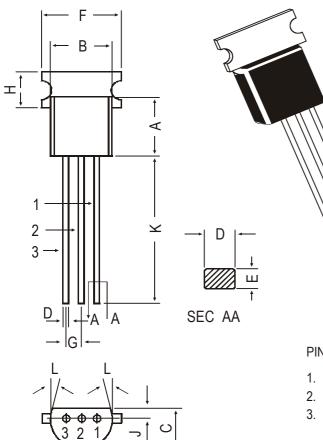
Amplifier Transistors.

ABSOLUTE MAXIMUM RATINGS(Ta=25° C unless specified otherwise)

DESCRIPTION	SYMBOL		VALUE		UNIT
Collector -Emitter Voltage	V_{CES}		25		V
Collector -Emitter Voltage	V_{CEO}		20		V
Emitter Base Voltage	V _{EBO}		5		V
Collector Current Continuous	I _C		1		А
Total Power Dissipation @T _A =25°C	P _D		1.0		W
Derate Above =25°C			6.4		mW/ºC
Total Power Dissipation @T _c =25°C	P _D		2.75		W
Derate Above =25°C			22		mW/ºC
Operating and Storage Junction	T _i , T _{sta}		-55 to +150		°C
Temperature Range					
THERMAL RESISTANCE					
Junction to Case	R _{th(j-c)}		45		°C/W
Juction to Ambient	R _{th(j-a)}		156		°C/W
ELECTRICAL CHARACTERISTICS (Ta DESCRIPTION		s specified otherwise TEST CONDITION) MIN	MAX	UNIT
Collector Emitter Breakdown Voltage	V _{CEO}	$I_{\rm C}$ =10mA, $I_{\rm B}$ =0	20		V
Collector Base Breakdown Voltage	V _{CBO}	I _C =100μA, I _F =0	25		
					V
Emitter Base Breakdown Voltage		•			V V
Emitter Base Breakdown Voltage Collector Cut off Current	V _{EBO}	I _E =100μA, I _C =0	5	10	V
Emitter Base Breakdown Voltage Collector Cut off Current		I _E =100μA, I _C =0 V _{CB} =25V, I _E =0		10 1	
	V _{EBO}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$			V
Collector Cut off Current	V _{EBO} I _{CBO}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$		1	V μA
Collector Cut off Current	V _{EBO} I _{CBO}	I_{E} =100µA, I_{C} =0 V_{CB} =25V, I_{E} =0 I_{E} =0, V_{CB} =25V, T_{j} =150°C V_{EB} =5V, I_{C} =0			ν μΑ μΑ
Collector Cut off Current Emitter Cut off Current Base Emitter on Voltage	V _{EBO} I _{CBO} I _{EBO} V _{BE(on)}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$ $V_{EB}=5V, I_{C}=0$ $I_{C}=1A, V_{CE}=1V$		1 10 1	V μA
Collector Cut off Current Emitter Cut off Current Base Emitter on Voltage Collector Emitter Saturation Voltage	V _{EBO} I _{CBO} V _{BE(on)} V _{CE(sat)}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$ $V_{EB}=5V, I_{C}=0$ $I_{C}=1A, V_{CE}=1V$ $I_{C}=1A, I_{B}=100mA$	5	1 10	ν μΑ ν
Collector Cut off Current Emitter Cut off Current Base Emitter on Voltage	V _{EBO} I _{CBO} I _{EBO} V _{BE(on)}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$ $V_{EB}=5V, I_{C}=0$ $I_{C}=1A, V_{CE}=1V$		1 10 1	ν μΑ ν
Collector Cut off Current Emitter Cut off Current Base Emitter on Voltage Collector Emitter Saturation Voltage	V _{EBO} I _{CBO} V _{BE(on)} V _{CE(sat)}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$ $V_{EB}=5V, I_{C}=0$ $I_{C}=1A, V_{CE}=1V$ $I_{C}=1A, I_{B}=100MA$ $I_{C}=50MA, V_{CE}=1V$	5	1 10 1 0.5	ν μΑ ν
Collector Cut off Current Emitter Cut off Current Base Emitter on Voltage Collector Emitter Saturation Voltage	V _{EBO} I _{CBO} V _{BE(on)} V _{CE(sat)}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$ $V_{EB}=5V, I_{C}=0$ $I_{C}=1A, V_{CE}=1V$ $I_{C}=1A, I_{B}=100mA$ $I_{C}=5mA, V_{CE}=10V$	5 50 85	1 10 1 0.5	ν μΑ ν
Collector Cut off Current Emitter Cut off Current Base Emitter on Voltage Collector Emitter Saturation Voltage DC Current Gain	V _{EBO} I _{CBO} V _{BE(on)} V _{CE(sat)}	$I_{E}=100\mu A, I_{C}=0$ $V_{CB}=25V, I_{E}=0$ $I_{E}=0, V_{CB}=25V,$ $T_{j}=150^{\circ}C$ $V_{EB}=5V, I_{C}=0$ $I_{C}=1A, V_{CE}=1V$ $I_{C}=1A, I_{B}=100MA$ $I_{C}=50MA, V_{CE}=1V$	5 50 85	1 10 1 0.5	ν μΑ ν

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	DIM	MIN.	MAX.	
All diminsions in mm.	А	4.32	5.33	
	В	4.45	5.20	
	С	3.18	4.19	
	D	0.41	0.55	
	Е	0.35	0.50	
	F		5.40	
	G	1.14	1.40	
	Н		2.54	
nsic	Κ	12.70		
dimi	L	5 DEG		
All (J	1.14	1.53	

PIN CONFIGURATION

3²1

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-237 Bulk	1K/polybag	240 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	26.2 kgs
TO-237 T&A	2K/ammo box	725 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	13.8 kgs

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Disclaimer

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